Lonsdaleite Films with Nanometer Thickness

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ABSTRACT: We investigate the properties of potentially the stiffest quasi-2-D films with lonsdaleite structure. Using a combination of ab initio and empirical potential approaches, we analyze the elastic properties of lonsdaleite films in both elastic and inelastic regimes and compare them with graphene and diamond films. We review possible fabrication methods of lonsdaleite films using the pure nanoscale “bottom-up” paradigm: by connecting carbon layers in multilayered graphene. We propose the realization of this method in two ways: by applying direct pressure and by using the recently proposed chemically induced phase transition. For both cases, we construct the phase diagrams depending on temperature, pressure, and film thickness. Finally, we consider the electronic properties of lonsdaleite films and establish the nonlinear dependence of the band gap on the films’ thicknesses and their lower effective masses in comparison with bulk crystal.

SECTION: Physical Processes in Nanomaterials and Nanostructures

Lonsdaleite is a carbon allotrope with a hexagonal lattice, often called hexagonal diamond due to its crystal structure. Since it was first observed in the Canyon Diablo meteorite by Foote1 and later by Frondel and Marvin,2 this phase was identified only as an incorporation in diamond matrix through topological defects such as stacking faults or twin boundaries.3–5 The fraction of the lonsdaleite phase was usually tiny and only recently was a 50% lonsdaleite found.6 Hexagonal diamond has never been obtained as a freestanding single crystal. Because of this, lonsdaleite is considered a purely hypothetical object. However, theoretical predictions show the great promise of this structure. Lonsdaleite is simulated to be over 50% harder than diamond on the ⟨100⟩ face and is shown to resist indentation pressures up to 152 GPa. Diamond breaks at only 97 GPa, making lonsdaleite one of the hardest crystals.7

Current synthesis methods do not allow us to create lonsdaleite crystals for applications, but the nanoscale “bottom-up” paradigm allows us to fabricate hexagonal diamond films of nanometer thickness from smaller objects such as graphene. We can assume that lonsdaleite nanofilms can be fabricated by the chemical junction of layers in multilayered graphene due to the number of theoretical predictions8–10 and experimental confirmations11–13 of the diamondization of multilayered graphene. Graphene layers can be connected by using two different driving forces: direct pressure13 and the chemical adsorption of adatoms on the multilayer graphene surface.8–12 The last approach was named “chemically induced phase transition”14. The sp³-hybridized carbon films have drawn a lot of attention due to interesting physical properties. A number of papers were published in recent years with description of their electronic,8,9,15 magnetic,16 and elastic17 properties. Lonsdaleite films of nanometer thickness can also be of interest because they could combine the high elastic constants of bulk crystal with the flexibility and high carrier mobility of thin carbon films.5 We can also expect that because of their similarity to nanometer-thick diamond films lonsdaleite films will display electronic properties that depend on the film’s thickness.

We began our study with analysis of the atomic structure and stability of nanometer thick lonsdaleite films with crystallographic surfaces (1010), (1110), and (0001). We found the critical size at which lonsdaleite film with a clean surface splits into the AA- and AA'-stacked graphene. We then investigated the phase transition from multilayered graphene to lonsdaleite films. The comparison of the ab initio computed Gibbs free energies allowed us to obtain the phase diagram P(T) as a function of film’s thickness. We considered the effect of chemically induced phase transition for films with a hydrogenated surface (named diamanes8) and found the conditions for when the pressure of phase transition formally turns negative. The mechanical properties of lonsdaleite films were obtained and compared with diamond films with (111) surface. The elastic constants of the films were estimated, and the
behavior of the films under critical strain was investigated. We found that lonsdaleite films are second in stiffness only to bulk lonsdaleite and graphene but display the same flexibility as diamond films. Finally, we studied the electronic properties of films. The band-gap dependence on the thickness of lonsdaleite films was obtained, and its nonlinear behavior was discussed. The carrier effective masses in the films were determined. It was found that the effective masses of conduction electrons in lonsdaleite films are lower than the effective masses of electrons in bulk case and asymptotically approach the bulk case effective masses as the film thickness increases.

Hydrogenated graphene can be considered as periodically connected cyclohexane carbon rings. Therefore, the conformers of cyclohexane dictate the conformers of graphene. The cyclohexane conformer “boat” corresponds to two graphene conformers: “boat1” (also called just “chair”, see Figure 1c) and “boat2” (also called “armchair”, see Figure 1b), whereas the conformer “chair” corresponds to graphene conformer “chair1” (also called “washboard”, see Figure 1a) and “chair2” (also called “zigzag”).

All of these graphene conformers can be considered as first members of the sp3-hybridized film families with various crystallographic surface orientations. In particular, conformers “boat1” and “boat2” are the first members of lonsdaleite-type films with (10̅10) (Figure 1d) and (2̅110) (Figure 1e) surfaces, respectively. Graphene conformer “chair1” belongs to both the group of diamond films with (11̅1) surface and the group of lonsdaleite films with (0001) surface depending on how its graphene layers are stacked (Figure 1f). Multilayered graphene could have AA′, AA, AB, or ABC stacking with nearly the same energy, as shown experimentally. AA′ stacking of multilayered graphene forms the intermediate state between AA and AB types of stacking, where the graphene planes are translated by a half width of the hexagon and can form together with AA stacked graphene. The chemical connection of AA′ graphene layers leads to the formation of lonsdaleite films with (10̅10) surface, whereas AA stacking is the base for the formation of (2̅110) and (0001) films.

First, the stability of the lonsdaleite films was analyzed. The structure of sp3-hybridized nanoclusters was exposed to surface effects that cause the graphitization process or the transformation of the outer carbon layers to graphene. This process was directly observed in diamond nanoclusters and nanowires and can play a major role in the stability of the considered films due to their atomic thickness.

It was found that among the films with clean (10̅10) surfaces with thicknesses from 2.86 (two layers) to 17.92 Å (nine layers), only the thinnest film is unstable and splits to bilayered graphene. Investigation of the films with (2̅110) surface shows that such structures are not susceptible to graphitization and even bilayered lonsdaleite film is stable.

Lonsdaleite films with clean (0001) surface are the most exposed to graphitization. These films become stable only when they are thicker than 10.8 Å (six layers), but the outer layers split into graphene. This significantly differs from the case of diamond films with (11̅1) surface where only films with thickness <8.42 Å (five layers) are unstable.

The appearance of lonsdaleite structures as stacking faults or twin boundaries in diamond can be considered as lonsdaleite films implemented into diamond matrix. The possibility of isolating such a quasi-2-D object is intriguing, but available experimental data prevent the expectation of fabricating lonsdaleite films from bulk diamond. However, known “bottom-up” paradigm allows the fabrication of lonsdaleite structures from smaller objects such as graphene. The number of theoretical predictions and experimental observations of the diamondization of multilayered graphene allows us to assume that freestanding lonsdaleite films could be fabricated through the chemical connection of neighbored carbon layers in the stack.

Graphene films can be transformed to lonsdaleite films by applying direct pressure. The amount of pressure needed can
be evaluated by taking the difference between the free energies of multilayered graphene and lonsdaleite film and dividing by the difference between atomic volumes of graphite and bulk lonsdaleite.

We obtained a phase diagram of such transitions in the temperature range 0–2000 K, as shown in the Figure 2 by red lines. The obtained phase diagrams allow the estimation of the fabrication conditions for lonsdaleite films from multilayered graphene. In the experimental paper, the formation of sp hybridized bonds between layers of seven-layered graphene at 16 GPa was reported. This high value agrees with our estimations that seven-layered graphene film should transit to lonsdaleite film with (0001) surface at 12 GPa (300 K); see Figure 2c.

The large phase transition pressure for the considered lonsdaleite films makes the formation process difficult and means the process requires the presence of a catalyst. The role of the catalyst can be played by the hydrogen adatoms on the surface of multilayered graphene. The binding of hydrogen atoms to the surface of multilayered graphene leads to the transformation of a practically chemically inert sp-hybridized carbon lattice to a semihydrogenated sp-hybridized film named graphone. This material is highly strained and unstable due to the unpaired electrons of carbon atoms not bounded with hydrogen. The formed graphene layer tends to compensate the dangling bonds by connection with the underlying graphene layer to form two-layered sp-hybridized carbon film. The sp-hybridized carbon atoms of the second layer also tend to connect with the next graphene layer and so on. The same story takes place from the bottom side of the multilayered graphene, and thus these processes go toward each other from the top to the bottom and vice versa. It was shown that such a process occurs without any activation barrier for the nanometer-sized films.

The comparison between the free energies of hydrogenated lonsdaleite film and multilayered graphene with adsorbed hydrogen atoms on the surface showed that the pressure of such a phase transition is formally below zero. This originated from the fact that binding energy of the graphene with the adsorbed hydrogen atoms on the surfaces is lower than the binding energy of the corresponding lonsdaleite film.

The feasibility of the proposed method is justified by available experimental data on the diamondization of multilayered graphene and amorphous carbon induced by hydrogenation. Other types of surface functionalization can be used instead of hydrogen as well. This was illustrated by experimental reports of the connection of graphene layers to diamond film by the chemical adsorption of hydroxyl groups and fluorine.

Different organizations of adatoms on the graphene surface could lead to the formation of every graphane conformer considered in the paper and the formation of lonsdaleite films with (1010), (2110), and (0001) surfaces. Therefore, the control over the organization of adsorbed atoms onto the graphene surface is critical in this issue and can depend on the adatom’s type and upon external conditions.

Reference 19 supposes that the structure of the graphane/fluorographene surface can contain several phases divided by grain boundary. In the case of thicker lonsdaleite films, such a situation cannot be realized due to the high lattice strain caused by neighboring different crystallographically oriented surfaces with different symmetry and lattice parameters. It can be supposed that once formed, one type of surface in one region will propagate to the whole film structure.

We then investigated in detail the elastic properties of the lonsdaleite films. First, we estimated the 2-D elastic moduli for lonsdaleite films with (1010), (2110), and (0001) surfaces and diamond film with (111) surface by defining the stress tensor due to strain as $\sigma_{ij} = C_{ij} \eta_{ij}$. This tensor corresponds to in-plane isotropic linear elasticity. We neglect the ambiguous thickness of 2D films; therefore, the dimension of the elastic modulus is N/m. We obtained the stress–strain, $\sigma_{ij} = \eta_{ij}$, relationships by simulating the uniaxial strains in the armchair ($\eta_1$) and zigzag ($\eta_2$) directions (Figure 1). These relationships allow us to estimate the values of the elastic constants $C_{11}'$, $C_{12}'$, and $C_{44}'$. This tensor corresponds to in-plane isotropic linear elasticity. We neglect the ambiguous thickness of 2D films; therefore, the dimension of the elastic modulus is N/m. We obtained the stress–strain, $\sigma_{ij} = \eta_{ij}$, relationships by simulating the uniaxial strains in the armchair ($\eta_1$) and zigzag ($\eta_2$) directions (Figure 1). These relationships allow us to estimate the values of the elastic constants $C_{11}'$, $C_{12}'$, and $C_{44}'$. Films with (2110) and (0001) surfaces should display lower values. The values should approach each other as the film’s thickness increases. Calculated data support this assumption (Figure 3a). Additionally, the comparison between the $C_{11}'$ and $C_{12}'$ constants of lonsdaleite
and diamond films with the same thickness shows that lonsdaleite films are stiffer than the diamond films.

From the obtained elastic constants, the velocities of longitudinal and transverse acoustic waves can be estimated using the following relations:

\[ v_{LA} = \left( \frac{C_{11}'}{\rho_{2D}} \right)^{1/2} \]
\[ v_{TA} = \left( \frac{1}{2} \left( \frac{C_{11}'}{\rho_{2D}} - C_{12}' \right) \right)^{1/2} \]

where \( \rho_{2D} \) is the formal 2-D density (kg/m² units). Such valuable characteristics could be compared with the corresponding data of bulk diamond and lonsdaleite. It was shown that lonsdaleite films display higher values not only compared with diamond film but also when compared with all known solids except bulk lonsdaleite and graphene. It is also clearly seen that acoustic velocities increased with increasing film thickness and that the velocities asymptotically approached corresponding bulk values (Figure 3b).

Another important mechanical characteristic of carbon films is behavior under critical deformation. In experiments, the 2-D films are usually probed by indenting the center of each freestanding film with the tip of an atomic force microscope.\(^{36,37}\) We simulated this process using an empirical interatomic bond-order Brenner potential because of the large size (10⁴ to 4 × 10⁴ atoms) of the considered structures. The chosen approach is justified by successful application of the potential in numerous studies of elastic properties of graphene\(^{38}\) and diamond films.\(^{8}\)

The investigated lonsdaleite films had an equal radius (75 Å) with fastened edges, while the radius of the tip was nearly 10 times smaller than that in the experimental setup.\(^ {36,37}\) Deflection was carried out with a step of 0.2 Å. At each step, the system was relaxed using conjugated gradient minimization.

The pressure induced by the tip causes the C–C bonds to elongate as displayed by color gradient (see Figure 4a for single layered film with (1010) surface and Figure S1 in the Supporting Information for other studied films). The distribution of the strained bonds was directly related to the symmetry of the films. We plotted the dependence of critical deflection value (where films are punctured in the center, Figure 4a) upon the thickness of the films (Figure 4b). It was found that as their thickness increases, films become stiffer and more brittle. Surprisingly though, even four-layered films display very high elasticity, with a critical indentation depth.

\[ \text{Table 1. Relation between the Two-Dimensional Elastic Constants of Lonsdaleite Films with Different Crystallographic Orientation of Surfaces}^{a} \]

<table>
<thead>
<tr>
<th>(1010)</th>
<th>(2110)</th>
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<tr>
<td>C₁₁'</td>
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\(^{a}\)Corresponding bulk constants (from the ref 35): \( C_{11} = 1222.5 \text{ GPa}, \)
\( C_{12} = 106.8 \text{ GPa}, \)
\( C_{13} = 47.5 \text{ GPa}, \)
\( C_{33} = 1326.3 \text{ GPa}, \) and \( C_{44} = 459.4 \text{ GPa}. \)
(b) Dependence of the experimental works.36,37 Here which is the integrated equation for the force used in almost linearly with and (0001) surfaces and sti
conclusion that the considered structures display the highest two sets of data validates the chosen approaches and allows the DFT calculations; see Figure 4c. The close correspondence of compare the estimations by classical Brenner potential with values around 3.25 eV. The band gaps of the 5a. All graphane conformers show closely adjacent band gap
−1/(1.05 coe
110) surface) times smaller than that of their corresponding multilayered graphene to lonsdaleite for the corresponding symmetry direction. Heavy
multilayered graphene to lonsdaleite lm forms from the multilayered graphene by estimated the phase diagram fi
only 1.5 ((1010) surface), 2.2 ((2110) surface), and 1.4 ((0001) surface) times smaller than that of their corresponding monolayered structures. The same results were obtained for the diamond films with (111) surface.
The obtained dependence of the strain energy $E$ of the carbon sheet upon the deflection was fitted by the fourth-order polynomial $E(\delta) = \sigma^{2D}(2a)/(\delta^2/2a) + E^{2D}(q/2a)(\delta^2/4a^2) + E_\nu$ which is the integrated equation for the force used in experimental works.36,37 Here $\sigma^{2D}$ is the pretension of the film, $a$ is the radius of the structure, $\delta$ is the deflection of the atom in the center point, $E^{2D}$ is the stiffness coefficient, and $q = 1/(1.05 - 0.15\nu - 0.16\nu^2)$, where $\nu = 0.2$ is the Poisson coefficient for diamond.38 It was found that $E^{2D}$ values increase almost linearly with film thickness (Figure 4c). This coefficient is directly related to the $C_{11}$ modulus,37,39 which allows us to compare the estimations by classical Brenner potential with DFT calculations; see Figure 4c. The close correspondence of two sets of data validates the chosen approaches and allows the conclusion that the considered structures display the highest stiffness and flexibility.

Finally, we considered the electronic properties of the studied films. The band structures of the different graphane conformers and corresponding types of lonsdaleite films are similar and display semiconducting behavior. The band gap width dependence of hydrogenated films with (1010), (2110), and (0001) surfaces and films with nonpassivated clean (1010), (2110) surfaces upon the number of layers are shown in Figure 5a. All graphane conformers show closely adjacent band gap values around 3.25 eV. The band gaps of the films are lower than the band gaps of both graphane and bulk lonsdaleite (3.35 eV), which is evidence of the existence of a minimum in the band gap function of the film thickness. This nonlinear behavior can be explained by surface states and the quantum confinement effect.9,17 As the film thickness increases, the surface contribution to the electronic structure decreases. This leads to band gap augmentation due to an increase in the bulk contribution. All hydrogenated films display direct band gap, which allows us to assume the structures have applications in nanoelectronics and nano-optics, for example, use as an active laser medium. Films with clean surfaces display an additional extreme point in the width of the band gap function when the number of layers corresponded to four-layered films (Figure 5a). This extremum is related to the transition from direct band gap to indirect band gap.

One of the most important characteristics of semiconducting material is the effective mass of its carriers. The effective masses $m^* = \hbar^2(\partial^2E/\partial k^2)^{-1}$ of both electrons and holes along the main directions of symmetry for lonsdaleite films with different thicknesses were determined and are shown in Figure 5b. It was found that the electron effective masses of the films are lower than corresponding masses in bulk lonsdaleite, which allows us to assume that there is better electronic transport in such structures. In the case of films with (1010) surface, only electrons have effective masses lower than those in the bulk case. Heavy holes display much larger values for the thinnest films than holes in bulk lonsdaleite, and the effective masses decrease with increasing thickness nearly exponentially. The effective masses of heavy and light holes of hydrogenated lonsdaleite films with (2110) surface along the $\Gamma \rightarrow Y$ direction degenerate with increasing thickness and approach $0.695m_0$, which corresponds to the effective mass of the hole in lonsdaleite for the corresponding symmetry direction. Heavy and light holes of hydrogenated lonsdaleite films with (0001) surface demonstrate behavior practically independent of the thickness.

Lonsdaleite films with nanometer thickness were investigated for the first time. We discussed the stability of these films and estimated the phase diagram $P(T)$ for the transition from multilayered graphene to lonsdaleite film. Additionally, we studied the effect of chemically induced phase transition when lonsdaleite film forms from the multilayered graphene by chemical adsorption of hydrogen adatoms to the surface and extend the phase diagram for this case. We investigated the elastic and electronic properties of the lonsdaleite films. We
found that values of the elastic constants and the acoustic velocities of lonsdaleite films are higher than those for diamond films with the same thickness. This makes lonsdaleite films second in stiffness only to the bulk lonsdaleite and graphene. It was found that investigated films are highly flexible. The films display peculiar band structure with direct band gap and nonlinear behavior of the relation between its band gap width and the films thickness. It was found that the effective masses of conduction electrons of the films are lower than the corresponding masses in bulk lonsdaleite, which allows us to assume better electronic transport in such structures. The combination of the obtained properties makes quasi-2-D lonsdaleite films a promising material for electronic, chemical sensing, and optical applications as the thinnest semiconducting films with extremely high stiffness. This makes further investigations of sp$^3$-hybridized carbon films particularly intriguing.

COMPUTATIONAL DETAILS

All calculations of the atomic structure and electronic properties were performed using density functional theory (DFT)$^{30,41}$ in the generalized gradient approximation with the Perdew–Burke–Ernzerhof (PBE) exchange correlation functional,$^{42}$ as implemented into the VASP$^{43–45}$ package. The plane-wave energy cutoff was set to 500 eV, while the Brillouin zone was sampled using an $8 \times 8 \times 1$ Monkhorst–Pack grid. Atomic structure optimization was carried out when the maximum interatomic force became $<0.01$ eV/Å. The effective masses of both electrons and holes were determined using a k-point spacing smaller than 0.01 Å$^{-1}$. To avoid interaction between the neighboring diamond or graphene layers, we set the translation vector along the $c$ axis of the hexagonal supercells to be $>15$ Å.

To evaluate the accuracy of the chosen approach, we calculated and compared the atomic geometry and electronic and elastic properties of graphene and bulk diamond with corresponding experimental values. It was found that the DFT-PBE method predicts the structural parameters of a considered systems with an error $<0.05\%$ (compared with the experimental values). It was found that the DFT–PBE approach is validated by a number of reference papers $^{52,54}$ that calculated the phase diagram $P(T)$ of various materials.

The behavior of the films under critical strain was simulated in the framework of classical molecular dynamics with Brenner potential$^{55}$ implemented into LAMMPS package.$^{56}$

ASSOCIATED CONTENT

Supporting Information

Deformation sequence for lonsdaleite films with (1010), (0001), and (2110) surfaces. This material is available free of charge via the Internet at http://pubs.acs.org.

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Notes

The authors declare no competing financial interest.

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REFERENCES


$F_{\text{ib}}(T, V) = k_B T \int_0^\infty g(V, \omega) \ln \left[ 1 - \exp \left( -\frac{\hbar \omega}{k_B T} \right) \right] d\omega$

Here $g(\omega(P))$ is the phonon density of states at the given pressure, calculated using density functional perturbation theory.$^{53}$ After phonon density of states integration, zero-point and vibrational energies (for each chosen temperature) were calculated from the corresponding relations. Substitution of all calculated energy contributions into the equation for Gibbs free energy allows us to obtain the temperature-dependent phase transition pressure value. The chosen approach is validated by a number of reference papers$^{52,54}$ that calculated the phase diagram $P(T)$ of various materials.

The behavior of the films under critical strain was simulated in the framework of classical molecular dynamics with Brenner potential$^{55}$ implemented into LAMMPS package.$^{56}$

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